



18N60

Power MOSFET

18A, 600V N-CHANNEL POWER MOSFET

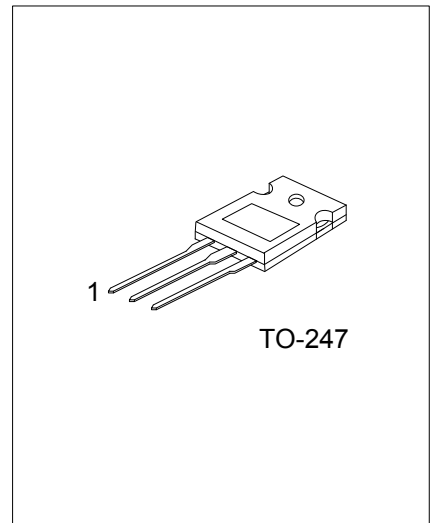
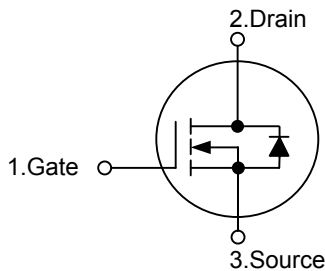
DESCRIPTION

The UTC **18N60** uses UTC's advanced proprietary, planar stripe, DMOS technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

FEATURES

- * $R_{DS(ON)} \leq 0.5\Omega @ V_{GS} = 10V$
- * Ultra Low Gate Charge (Typical 50nC)
- * Low Reverse Transfer Capacitance ($C_{RSS} = \text{Typical } 23\text{pF}$)
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

SYMBOL



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
18N60L-T47-T	18N60G-T47-T	TO-247	G	D	S	Tube

<p>18N60L-T47-T</p> <ul style="list-style-type: none"> (1)Packing Type (2)Package Type (3)Lead Free 	<ul style="list-style-type: none"> (1) T: Tube (2) T47: TO-247 (3) G: Halogen Free, L: Lead Free
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■ ABSOLUTE MAXIMUM RATINGS (T_C =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	600	V
Gate-Source Voltage		V _{GSS}	±30	V
Continuous Drain Current		I _D	18	A
Pulsed Drain Current		I _{DM}	45	A
Avalanche Current		I _{AR}	18	A
Avalanche Energy	Single Pulsed	E _{AS}	1000 (Note 2)	mJ
	Repetitive	E _{AR}	30	
Peak Diode Recovery dv/dt		dv/dt	10	V/ns
Power Dissipation		P _D	360	W
Junction Temperature		T _J	150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. L=6.18mH, I_{AS}=18A, V_{DD}=50V, R_G=25Ω, Starting T_J=25°C

■ THERMAL DATA

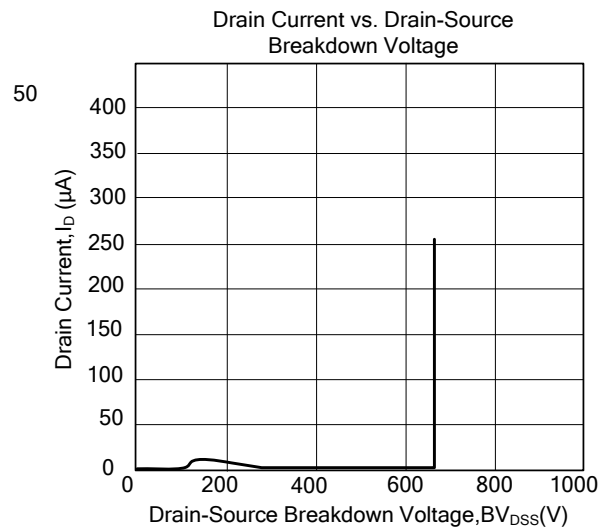
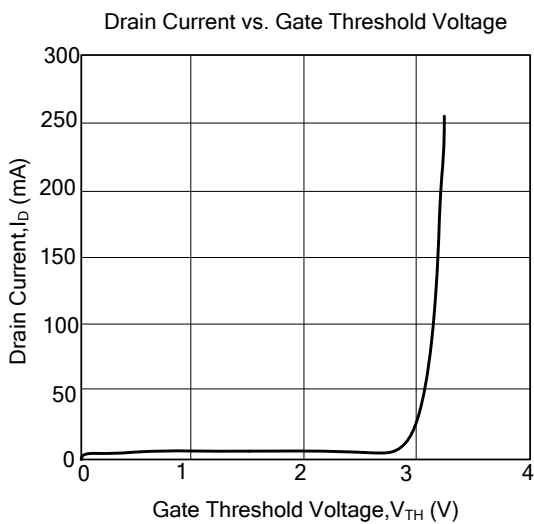
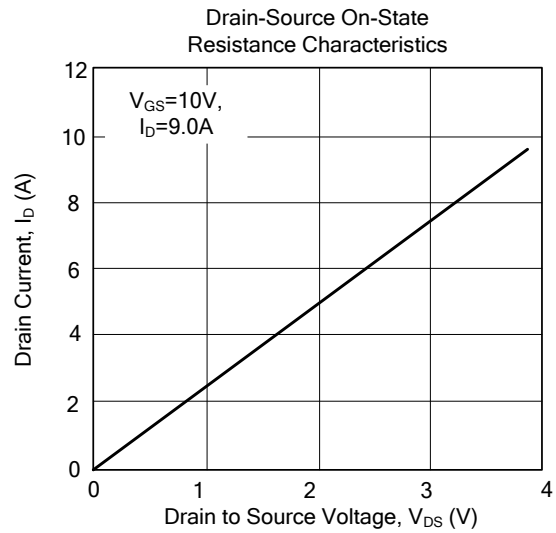
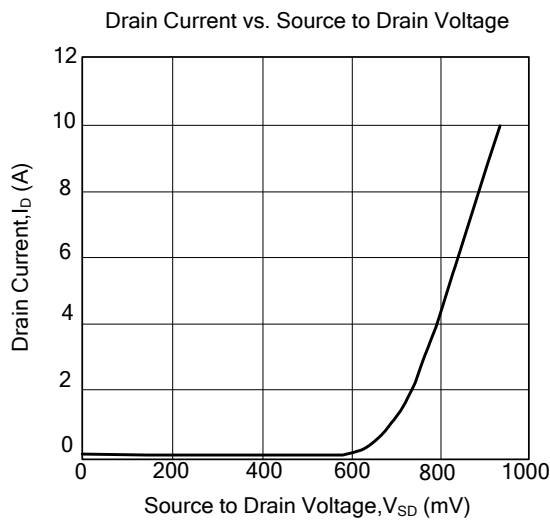
PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ _{JC}	0.35	°C/W

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	600			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =600V, V _{GS} =0V			25	μA
Gate-Body Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±30V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	2.0		4.0	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =9A (Note)		0.36	0.5	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{DS} =25V, V _{GS} =0V, f=1MHz		2500		pF
Output Capacitance	C _{OSS}			280		pF
Reverse Transfer Capacitance	C _{RSS}			23		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t _{D(ON)}	V _{GS} =10V, V _{DS} =0.5V _{DSS} , I _D =18A, R _G =5Ω (External)		21		ns
Turn-ON Rise Time	t _R			22		ns
Turn-OFF Delay Time	t _{D(OFF)}			62		ns
Turn-OFF Fall-Time	t _F			22		ns
Total Gate Charge	Q _G	V _{GS} =10V, V _{DS} =0.5V _{DSS} , I _D =9A		50		nC
Gate Source Charge	Q _{GS}			15		nC
Gate Drain Charge	Q _{GD}			18		nC
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Drain-Source Diode Forward Voltage	V _{SD}	I _F =I _S , V _{GS} =0V (Note)			1.5	V
Maximum Continuous Drain-Source Diode Forward Current	I _S	V _{GS} =0V			18	A
Maximum Pulsed Drain-Source Diode Forward Current	I _{SM}	Repetitive			54	A
Reverse Recovery Time	t _{rr}	V _{GS} =0V, dI _F /dt=100A/μs,			200	ns
Reverse Recovery Charge	Q _{RR}	I _S =18A, V _R =100V		0.8		μC

Note: Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.

TYPICAL CHARACTERISTICS



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